

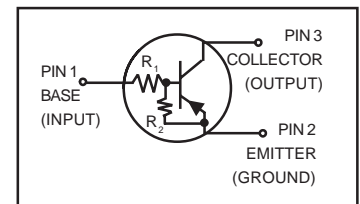
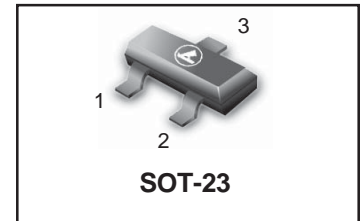
Bias Resistor Transistors

PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-23 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SOT-23 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel. Use the Device Number to order the 7 inch/3000 unit reel. Replace “T1” with “T3” in the Device Number to order the 13 inch/10,000 unit reel.
- We declare that the material of product compliance with RoHS requirements.

LMUN2110LT1G Series



MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	246 (Note 1.) 400 (Note 2.) 1.5 (Note 1.) 2.0 (Note 2.)	mW $^\circ\text{C/W}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	508 (Note 1.) 311 (Note 2.)	$^\circ\text{C/W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	174 (Note 1.) 208 (Note 2.)	$^\circ\text{C/W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

LMUN2110LT1G Series

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping
LMUN2110LT1G (Note 3.) LMUN2110LT3G	SOT-23	A6O	47	∞	3000/Tape & Reel 10,000/Tape & Reel
LMUN2111LT1G LMUN2111LT3G	SOT-23	A6A	10	10	3000/Tape & Reel 10,000/Tape & Reel
LMUN2112LT1G LMUN2112LT3G	SOT-23	A6B	22	22	3000/Tape & Reel 10,000/Tape & Reel
LMUN2113LT1G LMUN2113LT3G	SOT-23	A6C	47	47	3000/Tape & Reel 10,000/Tape & Reel
LMUN2114LT1G LMUN2114LT3G	SOT-23	A6D	10	47	3000/Tape & Reel 10,000/Tape & Reel
LMUN2115LT1G LMUN2115LT3G	SOT-23	A6E	10	∞	3000/Tape & Reel 10,000/Tape & Reel
LMUN2116LT1G LMUN2116LT3G	SOT-23	A6F	4.7	∞	3000/Tape & Reel 10,000/Tape & Reel
LMUN2130LT1G (Note 3.) LMUN2130LT3G	SOT-23	A6G	1.0	1.0	3000/Tape & Reel 10,000/Tape & Reel
LMUN2131LT1G LMUN2131LT3G	SOT-23	A6H	2.2	2.2	3000/Tape & Reel 10,000/Tape & Reel
LMUN2132LT1G LMUN2132LT3G	SOT-23	A6J	4.7	4.7	3000/Tape & Reel 10,000/Tape & Reel
LMUN2133LT1G LMUN2133LT3G	SOT-23	A6K	4.7	47	3000/Tape & Reel 10,000/Tape & Reel
LMUN2134LT1G (Note 3.) LMUN2134LT3G	SOT-23	A6L	22	47	3000/Tape & Reel 10,000/Tape & Reel
LMUN2136LT1G LMUN2136LT3G	SOT-23	A6N	100	100	3000/Tape & Reel 10,000/Tape & Reel
LMUN2137LT1G LMUN2137LT3G	SOT-23	A6P	47	22	3000/Tape & Reel 10,000/Tape & Reel
LMUN2138LT1G (Note 3.) LMUN2138LT3G	SOT-23	A6R	2.2	∞	3000/Tape & Reel 10,000/Tape & Reel
LMUN2140LT1G (Note 3.) LMUN2140LT3G	SOT-23	A6T	47	∞	3000/Tape & Reel 10,000/Tape & Reel

3. New devices. Updated curves to follow in subsequent data sheets.

LMUN2110LT1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector-Base Cutoff Current ($V_{CB} = 50\text{ V}, I_E = 0$)	I_{CBO}	–	–	100	nAdc
Collector-Emitter Cutoff Current ($V_{CE} = 50\text{ V}, I_B = 0$)	I_{CEO}	–	–	500	nAdc
Emitter-Base Cutoff Current ($V_{EB} = 6.0\text{ V}, I_C = 0$)	LMUN2110LT1G	–	–	0.1	mAdc
	LMUN2111LT1G	–	–	0.5	
	LMUN2112LT1G	–	–	0.2	
	LMUN2113LT1G	–	–	0.1	
	LMUN2114LT1G	–	–	0.2	
	LMUN2115LT1G	–	–	0.9	
	LMUN2116LT1G	–	–	1.9	
	LMUN2130LT1G	–	–	4.3	
	LMUN2131LT1G	–	–	2.3	
	LMUN2132LT1G	–	–	1.5	
	LMUN2133LT1G	–	–	0.18	
	LMUN2134LT1G	–	–	0.13	
	LMUN2136LT1G	–	–	0.05	
	LMUN2137LT1G	–	–	0.13	
LMUN2138LT1G	–	–	4.0		
LMUN2140LT1G	–	–	0.2		
Collector-Base Breakdown Voltage ($I_C = 10\ \mu\text{A}, I_E = 0$)	$V_{(BR)CBO}$	50	–	–	Vdc
Collector-Emitter Breakdown Voltage (Note 4.) ($I_C = 2.0\text{ mA}, I_B = 0$)	$V_{(BR)CEO}$	50	–	–	Vdc

4. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 5.)					
DC Current Gain ($V_{CE} = 10\text{ V}, I_C = 5.0\text{ mA}$)	LMUN2110LT1G	80	140	–	
	LMUN2111LT1G	35	60	–	
	LMUN2112LT1G	60	100	–	
	LMUN2113LT1G	80	140	–	
	LMUN2114LT1G	80	140	–	
	LMUN2115LT1G	160	250	–	
	LMUN2116LT1G	160	250	–	
	LMUN2130LT1G	3.0	5.0	–	
	LMUN2131LT1G	8.0	15	–	
	LMUN2132LT1G	15	27	–	
	LMUN2133LT1G	80	140	–	
	LMUN2134LT1G	80	130	–	
	LMUN2136LT1G	80	150	–	
	LMUN2137LT1G	80	140	–	
LMUN2138LT1G	160	350	–		
LMUN2140LT1G	120	250	–		
Collector-Emitter Saturation Voltage ($I_C = 10\text{ mA}, I_B = 0.3\text{ mA}$) ($I_C = 10\text{ mA}, I_B = 5\text{ mA}$) LMUN2130LT1G/LMUN2131LT1G ($I_C = 10\text{ mA}, I_B = 1\text{ mA}$) LMUN2115LT1G/LMUN2116LT1G/ LMUN2132LT1G/LMUN2133LT1G/ LMUN2134LT1G/LMUN2138LT1G/LMUN2140LT1G	$V_{CE(sat)}$	–	–	0.25	Vdc

LMUN2110LT1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 5.)					
Output Voltage (on) ($V_{CC} = 5.0\text{ V}$, $V_B = 2.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OL}	–	–	0.2	Vdc
LMUN2110LT1G		–	–	0.2	
LMUN2114LT1G		–	–	0.2	
LMUN2111LT1G		–	–	0.2	
LMUN2112LT1G		–	–	0.2	
LMUN2114LT1G		–	–	0.2	
LMUN2115LT1G		–	–	0.2	
LMUN2116LT1G		–	–	0.2	
LMUN2130LT1G		–	–	0.2	
LMUN2131LT1G		–	–	0.2	
LMUN2132LT1G		–	–	0.2	
LMUN2133LT1G		–	–	0.2	
LMUN2134LT1G		–	–	0.2	
LMUN2138LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 3.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$)		–	–	0.2	
LMUN2113LT1G		–	–	0.2	
LMUN2140LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 5.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$)		–	–	0.2	
LMUN2136LT1G		–	–	0.2	
($V_{CC} = 5.0\text{ V}$, $V_B = 4.0\text{ V}$, $R_L = 1.0\text{ k}\Omega$)		–	–	0.2	
LMUN2137LT1G		–	–	0.2	
Output Voltage (off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OH}	4.9	–	–	Vdc
LMUN2115LT1G					
LMUN2116LT1G					
LMUN2131LT1G					
LMUN2132LT1G					
LMUN2138LT1G					
LMUN2140LT1G					
($V_{CC} = 5.0\text{ V}$, $V_B = 0.050\text{ V}$, $R_L = 1.0\text{ k}\Omega$)					
LMUN2130LT1G					
Input Resistor	R_1	32.9	47	61.1	k Ω
LMUN2110LT1G		7.0	10	13	
LMUN2111LT1G		15.4	22	28.6	
LMUN2112LT1G		32.9	47	61.1	
LMUN2113LT1G		7.0	10	13	
LMUN2114LT1G		7.0	10	13	
LMUN2115LT1G		3.3	4.7	6.1	
LMUN2116LT1G		0.7	1.0	1.3	
LMUN2130LT1G		1.5	2.2	2.9	
LMUN2131LT1G		3.3	4.7	6.1	
LMUN2132LT1G		3.3	4.7	6.1	
LMUN2133LT1G		15.4	22	28.6	
LMUN2134LT1G		70	100	130	
LMUN2136LT1G		32.9	47	61.1	
LMUN2137LT1G		1.54	2.2	2.86	
LMUN2138LT1G		32.9	47	61.1	
LMUN2140LT1G					
Resistor Ratio	R_1/R_2	0.8	1.0	1.2	
LMUN2111LT1G/LMUN2112LT1G/ LMUN2113LT1G/LMUN2136LT1G/ LMUN2130LT1G/LMUN2131LT1G/ LMUN2132LT1G LMUN2114LT1G		0.17	0.21	0.25	
LMUN2115LT1G/LMUN2116LT1G/ LMUN2110LT1G/LMUN2138LT1G/LMUN2140LT1G		–	–	–	
LMUN2133LT1G		0.055	0.1	0.185	
LMUN2137LT1G		1.7	2.1	2.6	

5. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2111LT1G

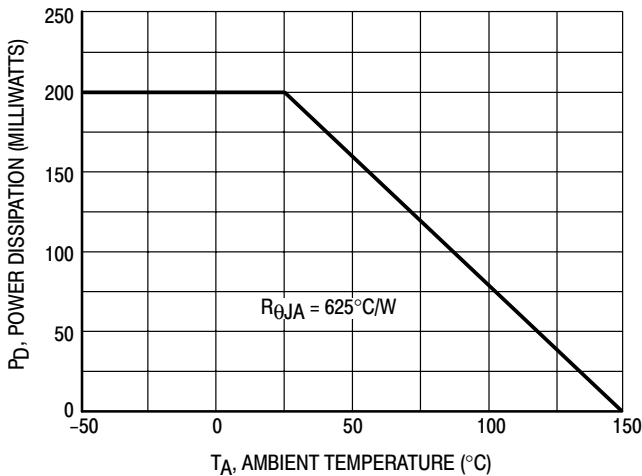


Figure 1. Derating Curve

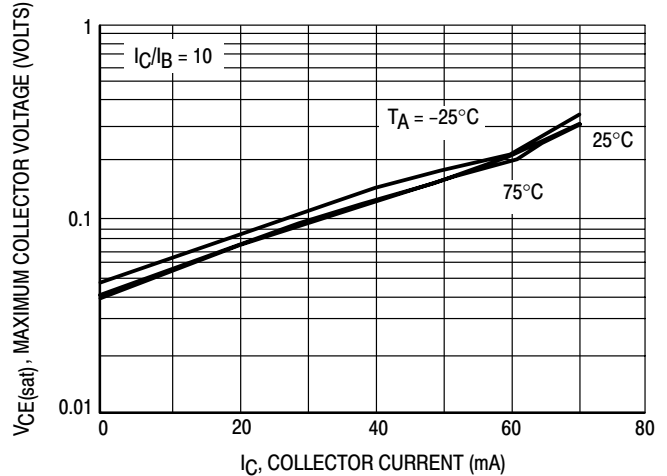


Figure 2. $V_{CE(sat)}$ versus I_C

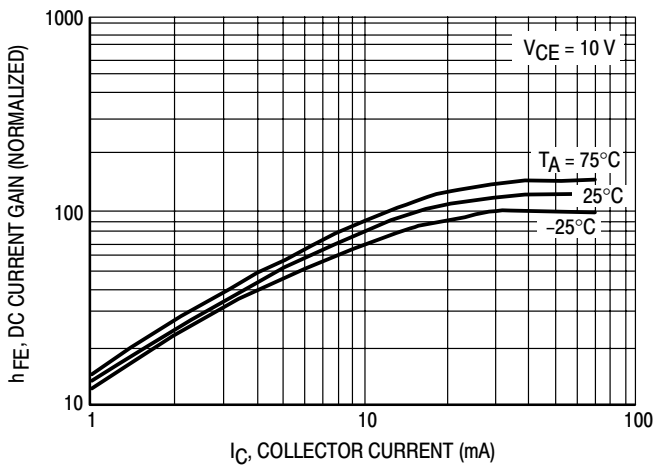


Figure 3. DC Current Gain

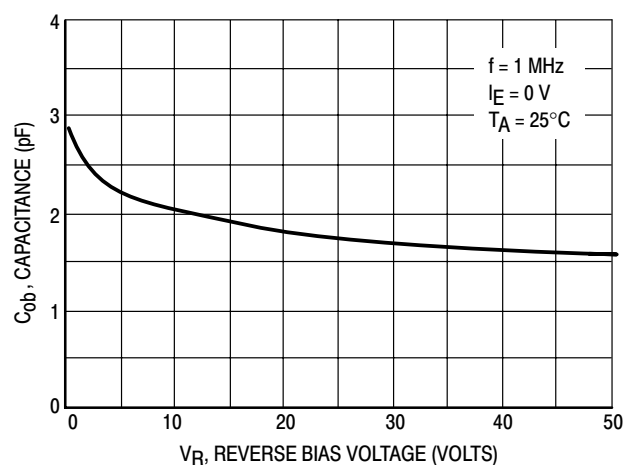


Figure 4. Output Capacitance

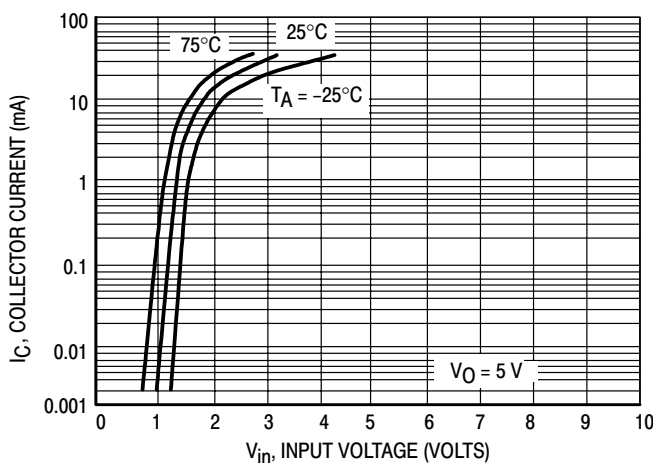


Figure 5. Output Current versus Input Voltage

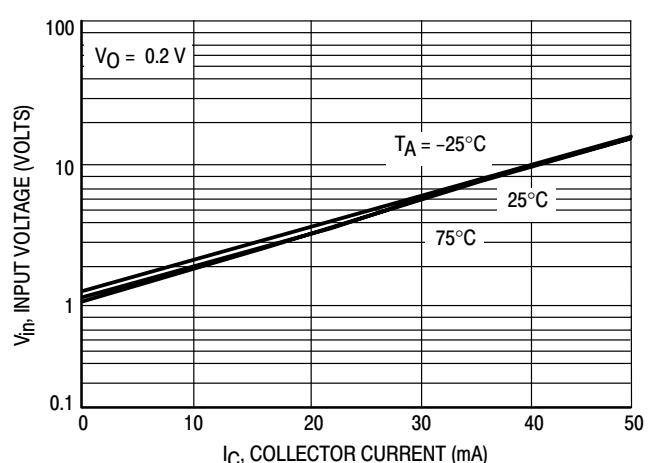


Figure 6. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2112LT1G

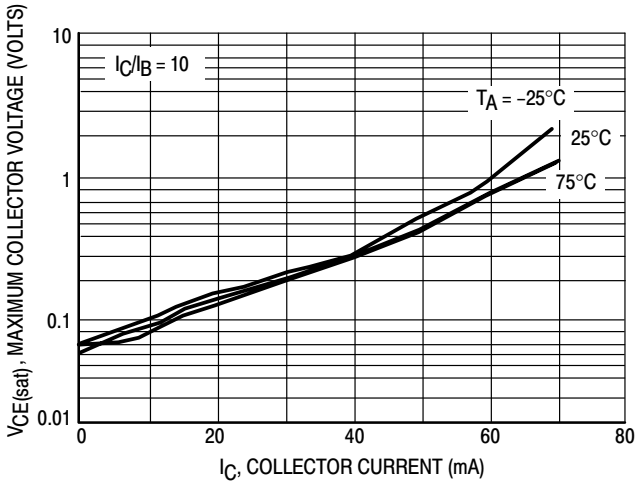


Figure 7. $V_{CE(sat)}$ versus I_C

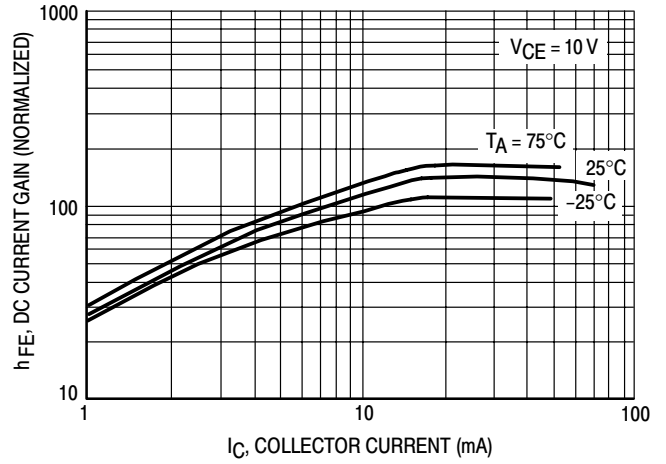


Figure 8. DC Current Gain

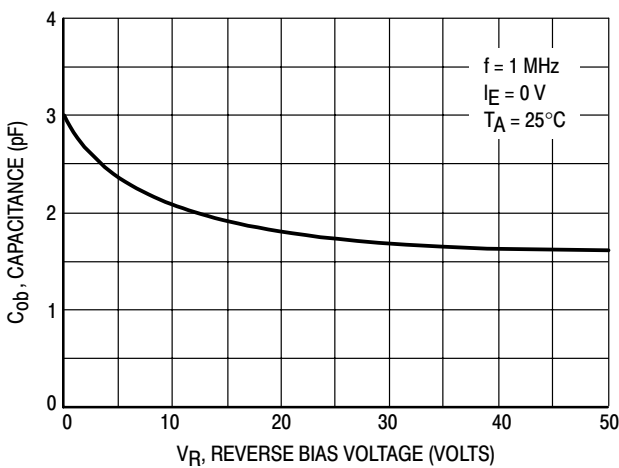


Figure 9. Output Capacitance

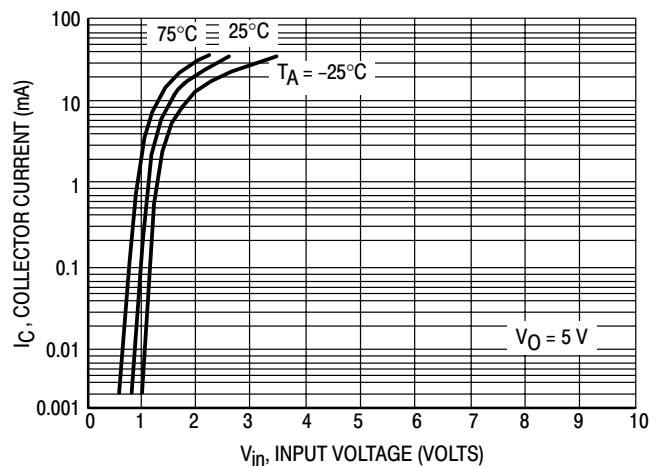


Figure 10. Output Current versus Input Voltage

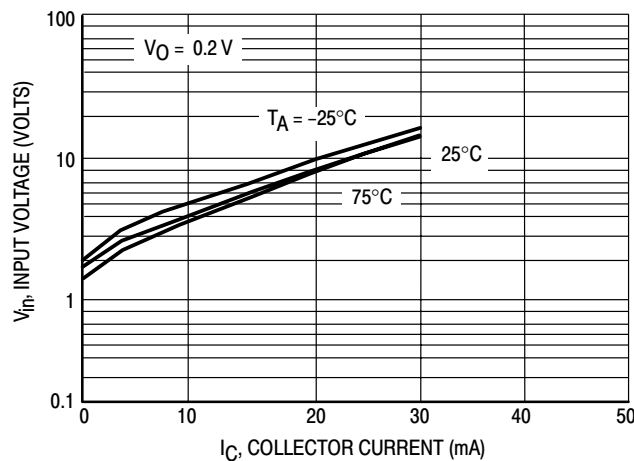


Figure 11. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2113LT1G

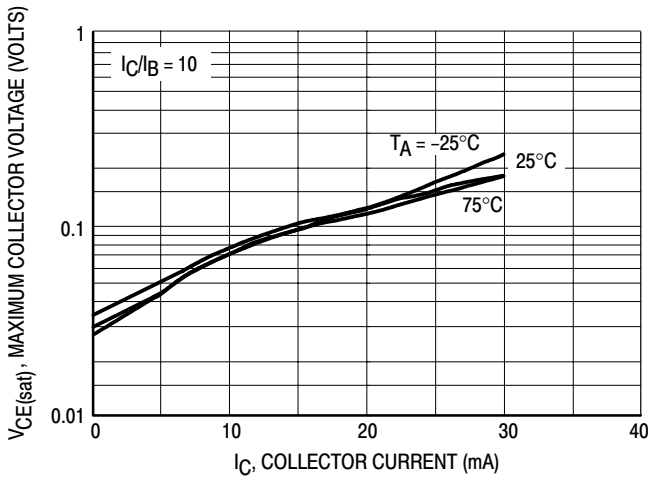


Figure 12. $V_{CE(sat)}$ versus I_C

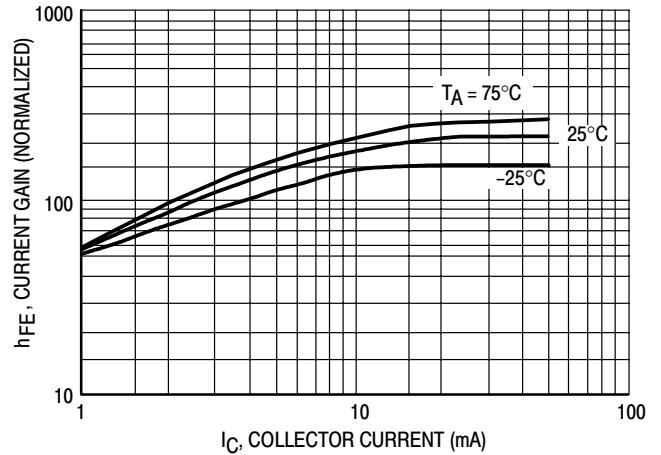


Figure 13. DC Current Gain

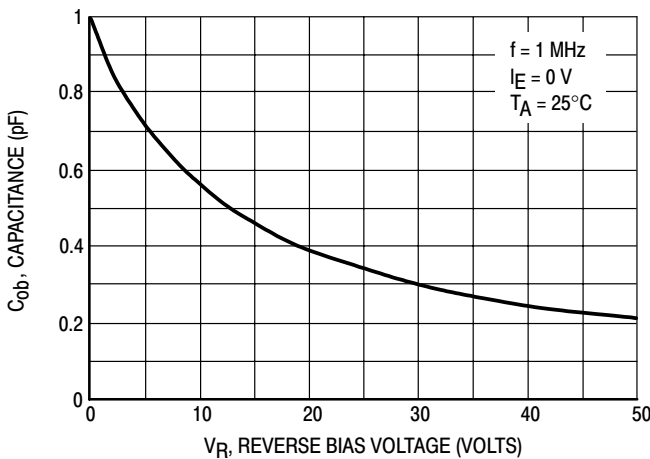


Figure 14. Output Capacitance

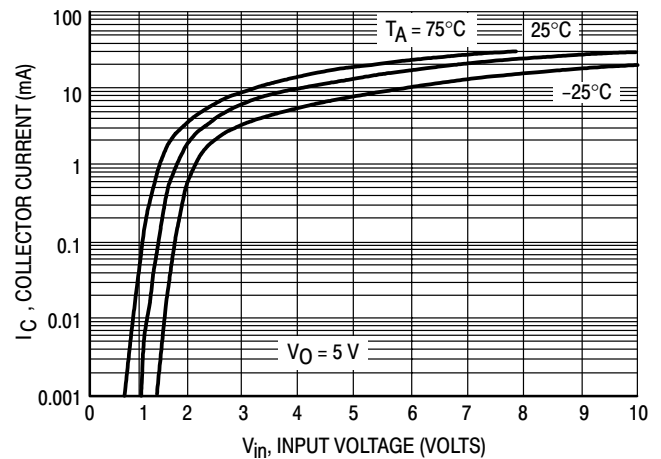


Figure 15. Output Current versus Input Voltage

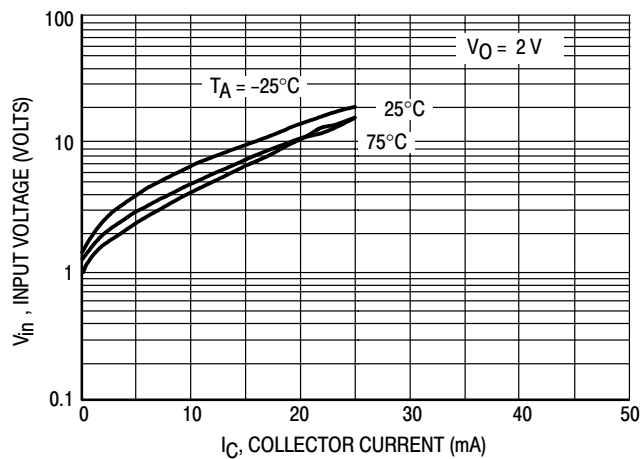


Figure 16. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2114LT1G

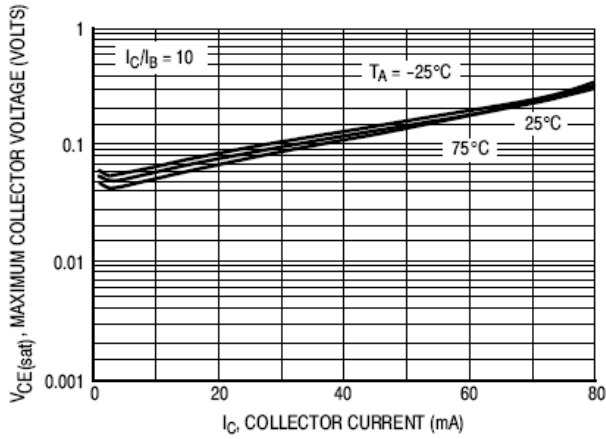


Figure 17. $V_{CE(sat)}$ versus I_C

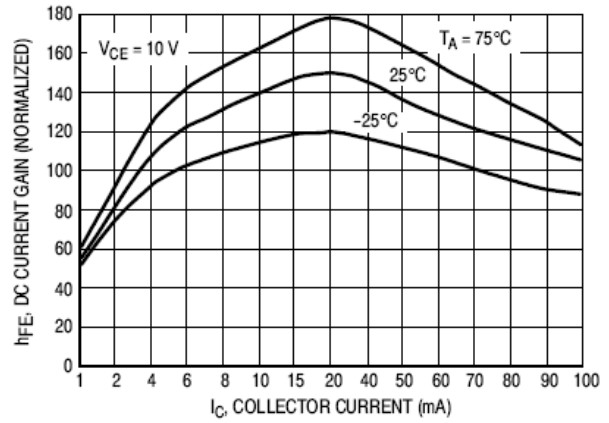


Figure 18. DC Current Gain

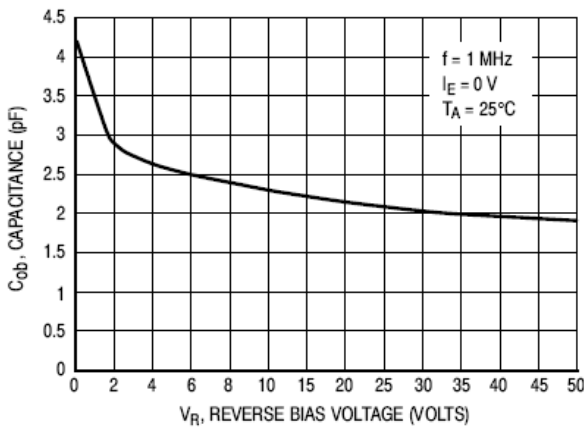


Figure 19. Output Capacitance

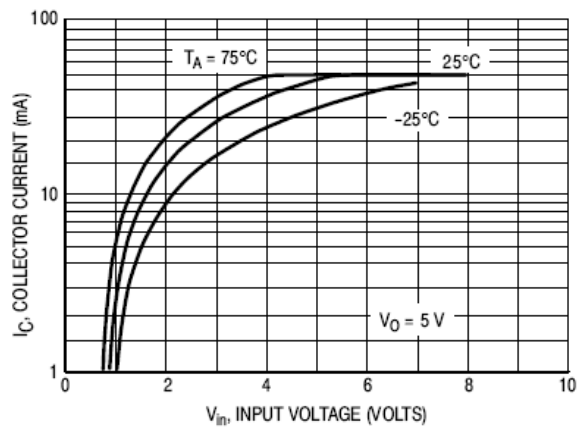


Figure 20. Output Current versus Input Voltage

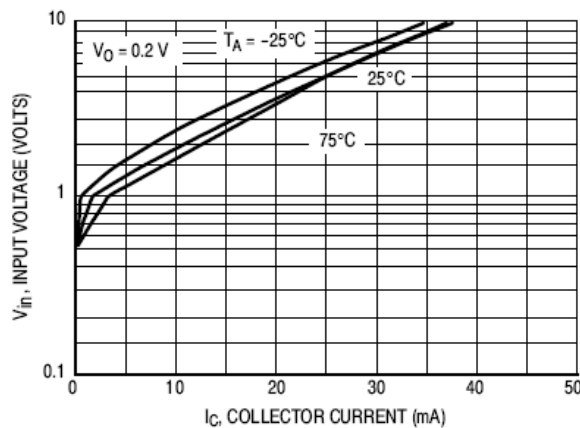


Figure 21. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2115LT1G

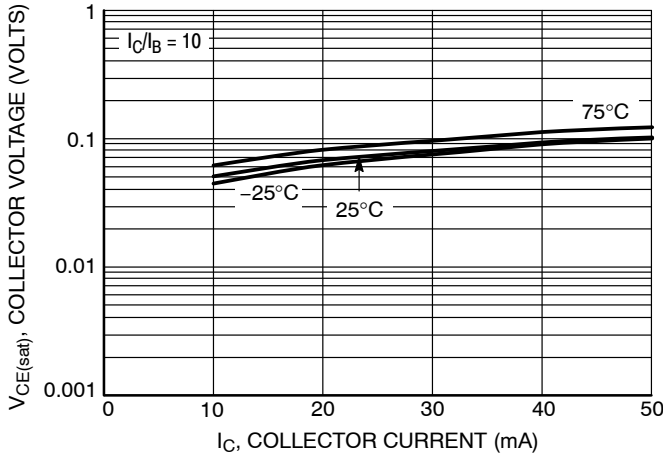


Figure 22. $V_{CE(sat)}$ versus I_C

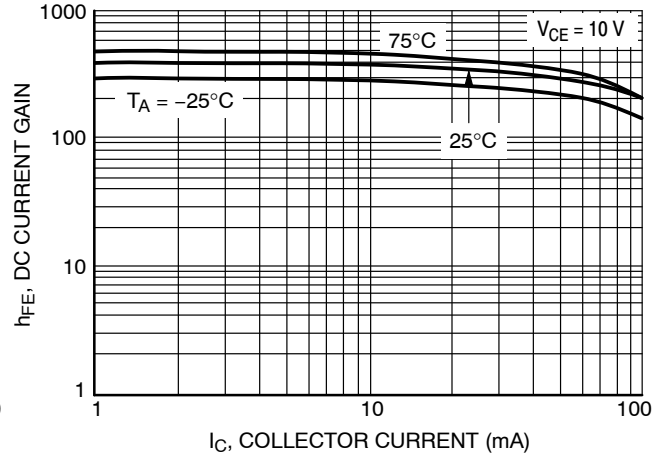


Figure 23. DC Current Gain

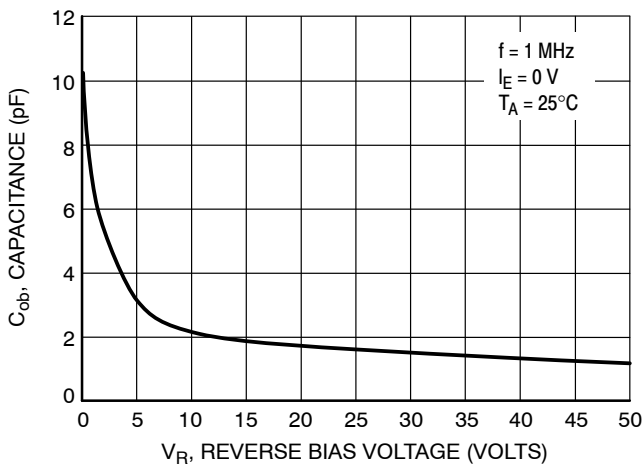


Figure 24. Output Capacitance

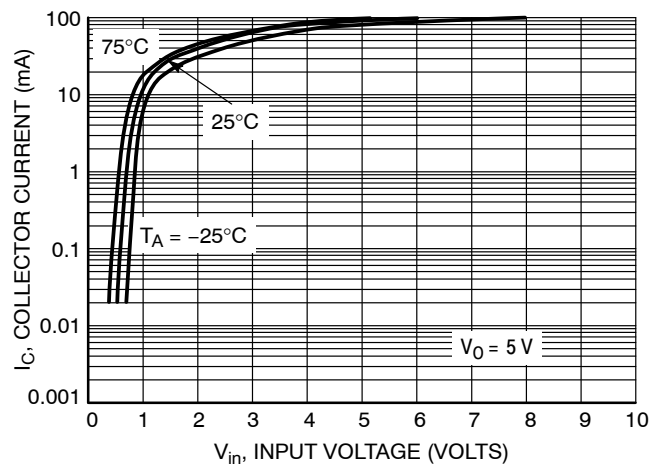


Figure 25. Output Current versus Input Voltage

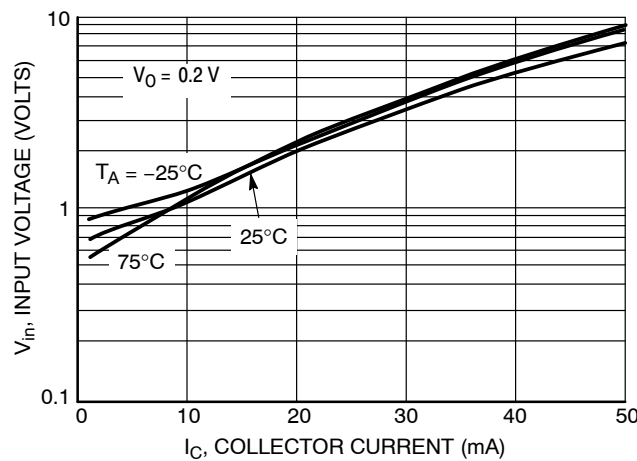


Figure 26. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2116LT1G

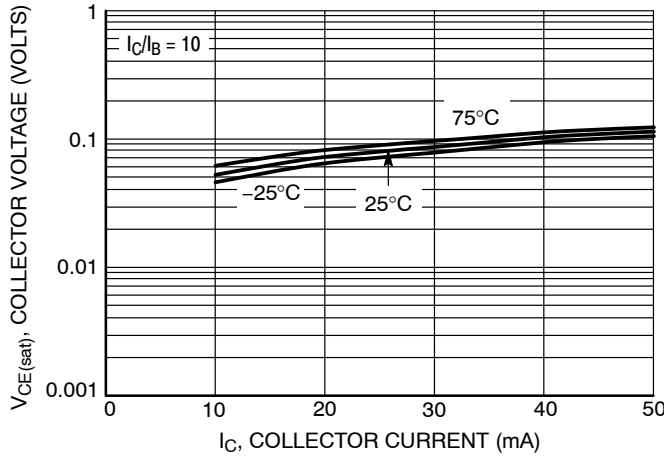


Figure 27. $V_{CE(sat)}$ versus I_C

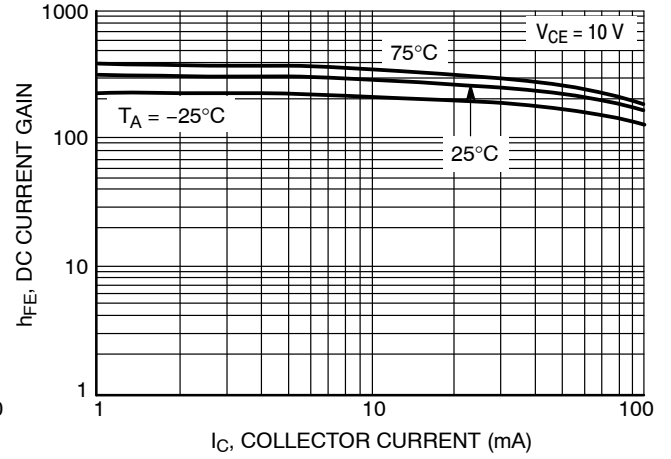


Figure 28. DC Current Gain

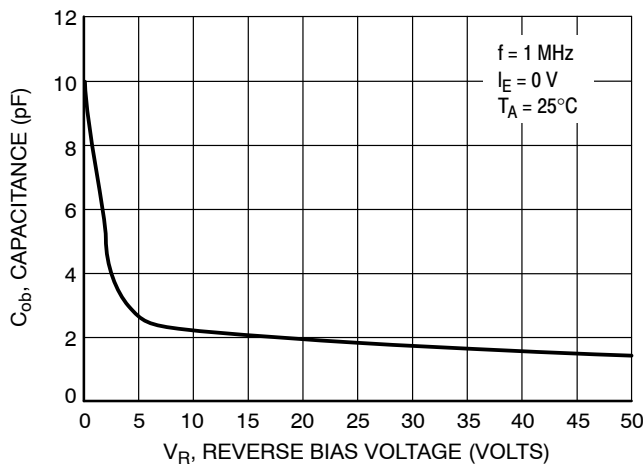


Figure 29. Output Capacitance

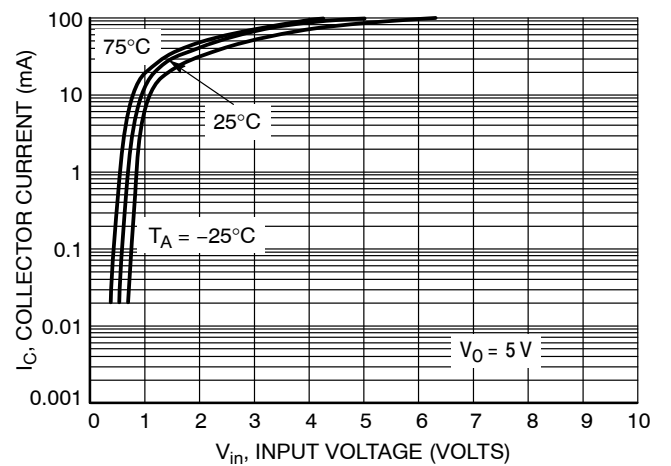


Figure 30. Output Current versus Input Voltage

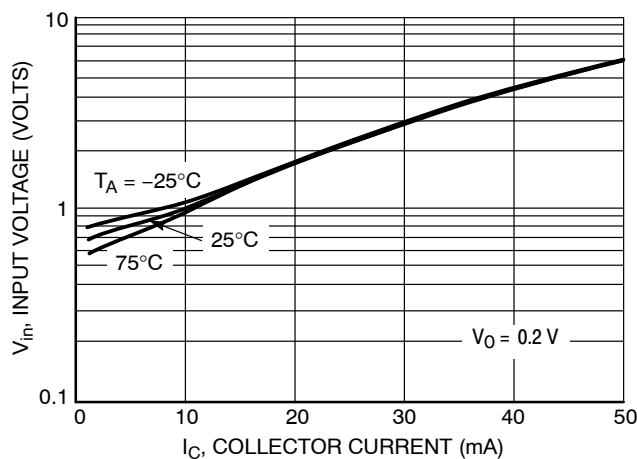


Figure 31. Input Voltage versus Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2131LT1G

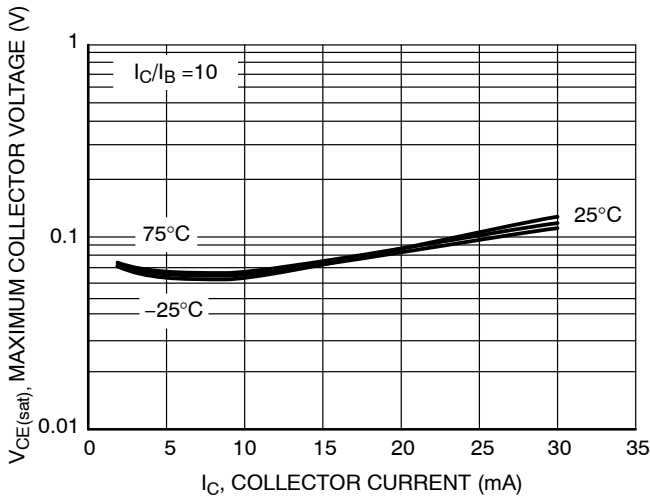


Figure 32. $V_{CE(sat)}$ vs. I_C

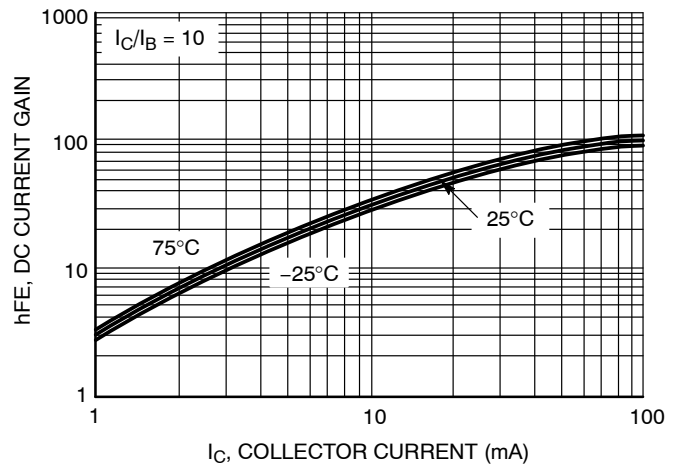


Figure 33. DC Current Gain

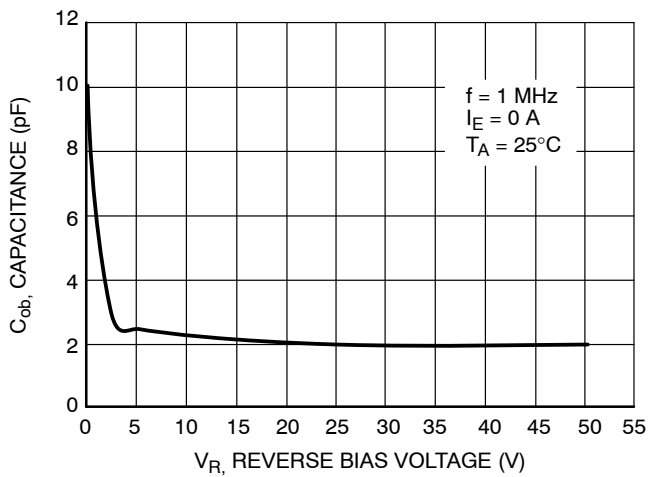


Figure 34. Output Capacitance

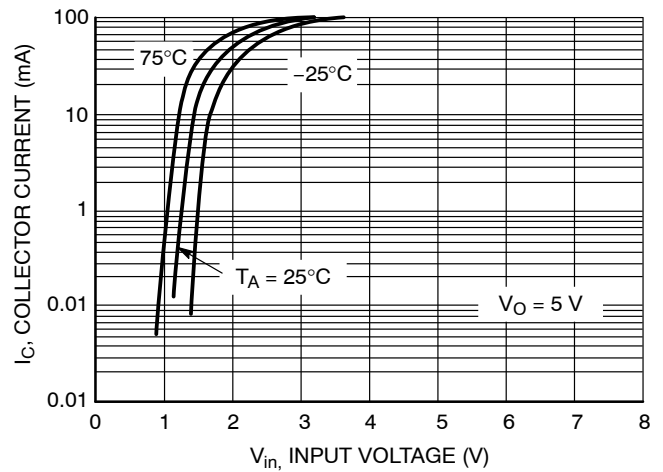


Figure 35. Output Current vs. Input Voltage

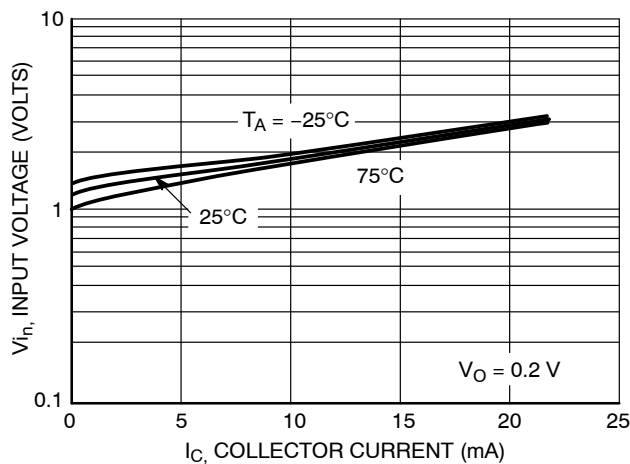


Figure 36. Input Voltage vs. Output Current

LMUN2110LT1G Series

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2132LT1G

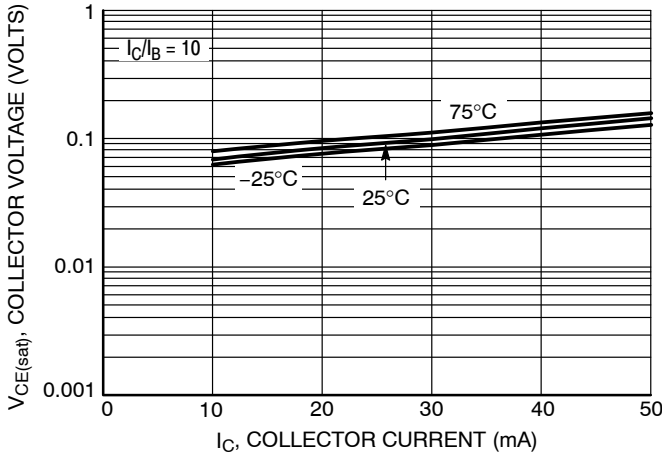


Figure 37. $V_{CE(sat)}$ versus I_C

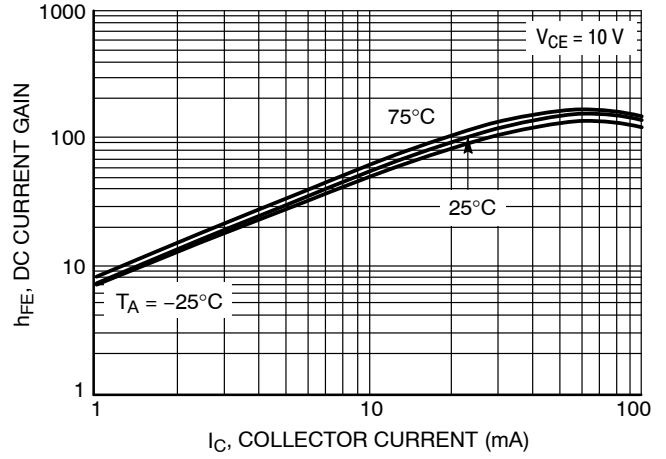


Figure 38. DC Current Gain

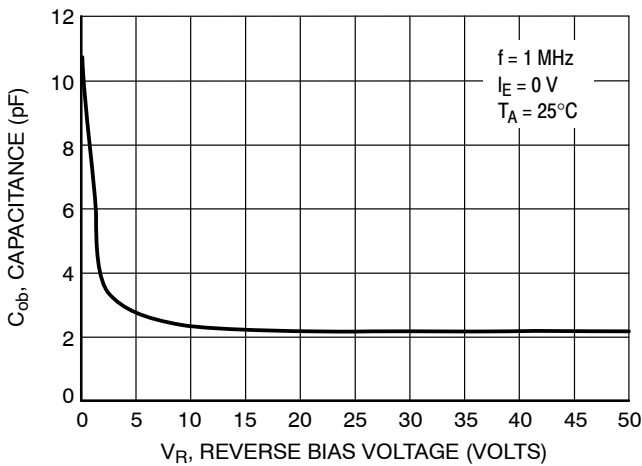


Figure 39. Output Capacitance

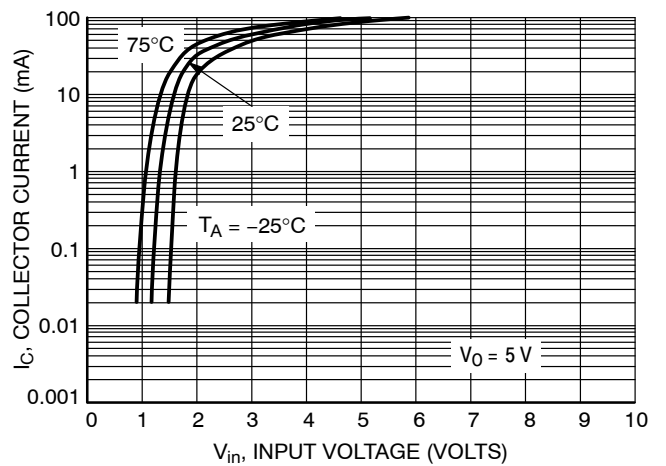


Figure 40. Output Current versus Input Voltage

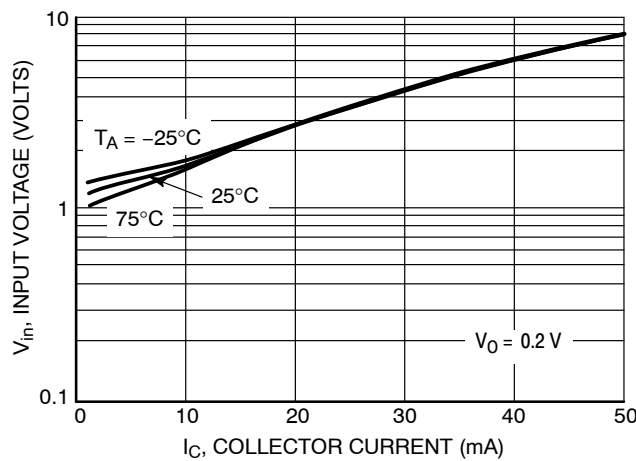


Figure 41. Input Voltage versus Output Current

TYPICAL ELECTRICAL CHARACTERISTICS LMUN2110LT1G Series
LMUN2133LT1G

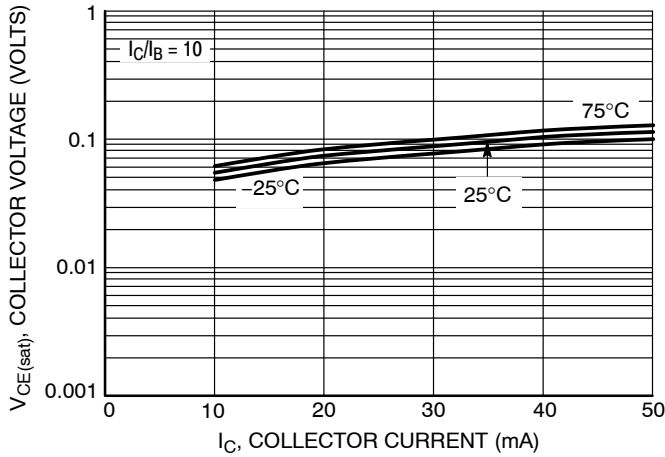


Figure 42. $V_{CE(sat)}$ versus I_C

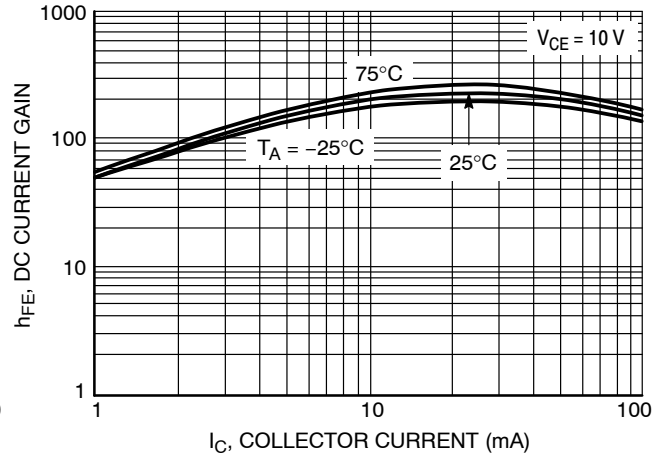


Figure 43. DC Current Gain

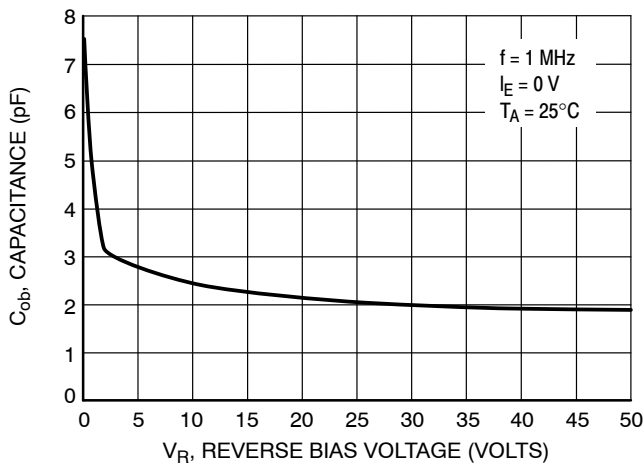


Figure 44. Output Capacitance

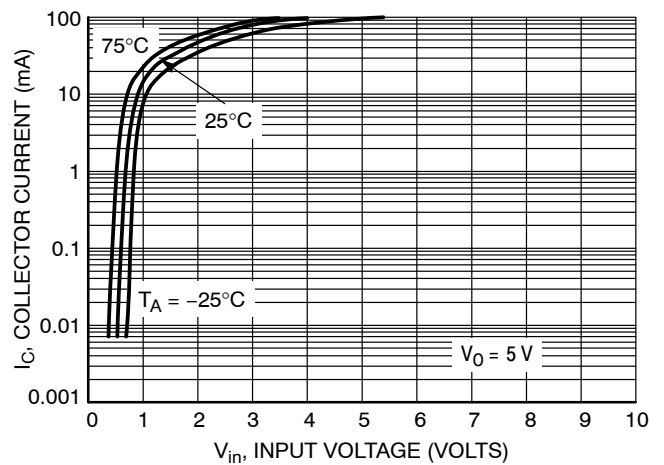


Figure 45. Output Current versus Input Voltage

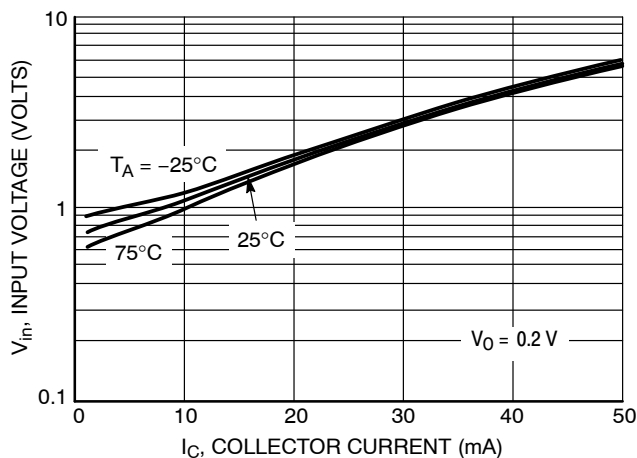


Figure 46. Input Voltage versus Output Current

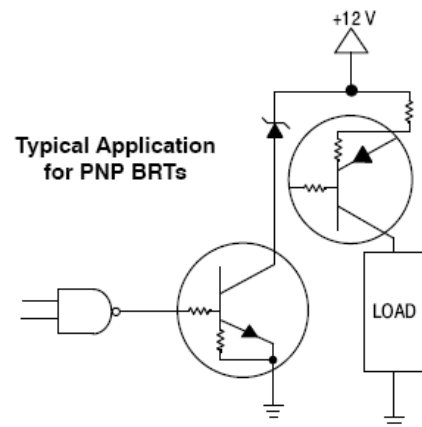


Figure 47. Inexpensive, Unregulated Current Source

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2136LT1G

LMUN2110LT1G Series

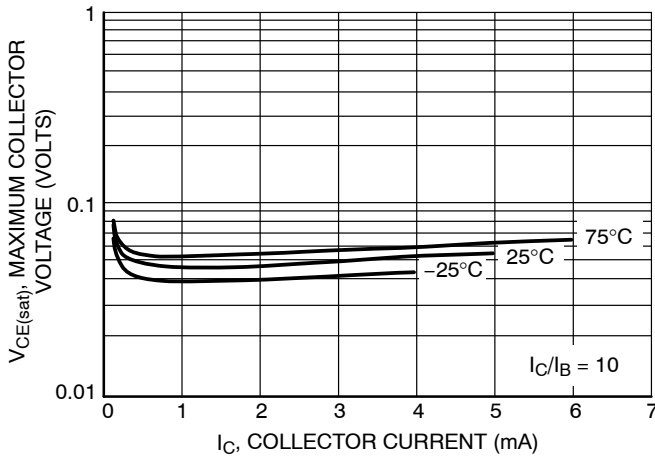


Figure 48. Maximum Collector Voltage vs. Collector Current

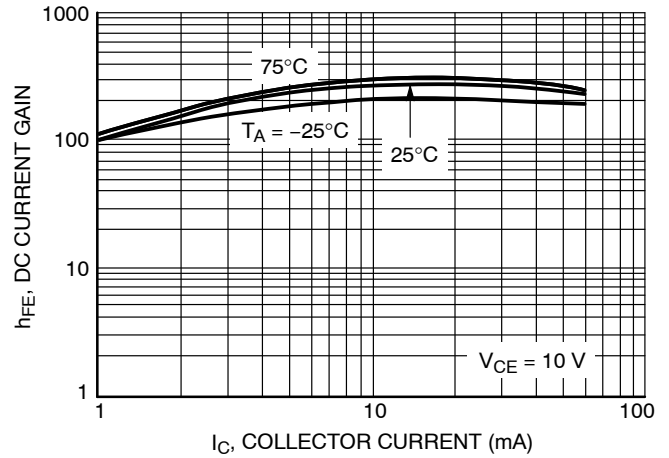


Figure 49. DC Current Gain

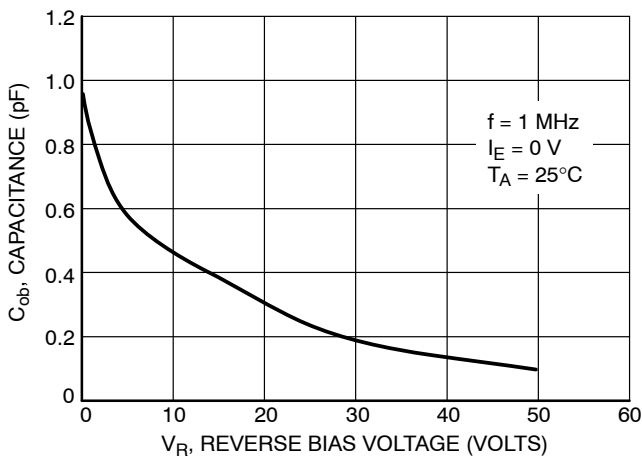


Figure 50. Output Capacitance

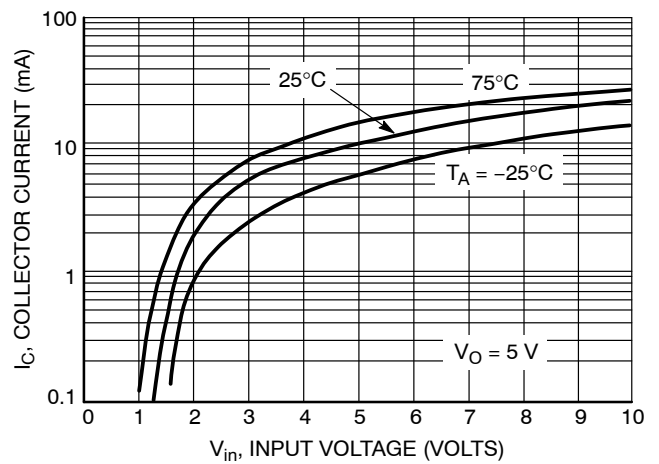


Figure 51. Output Current vs. Input Voltage

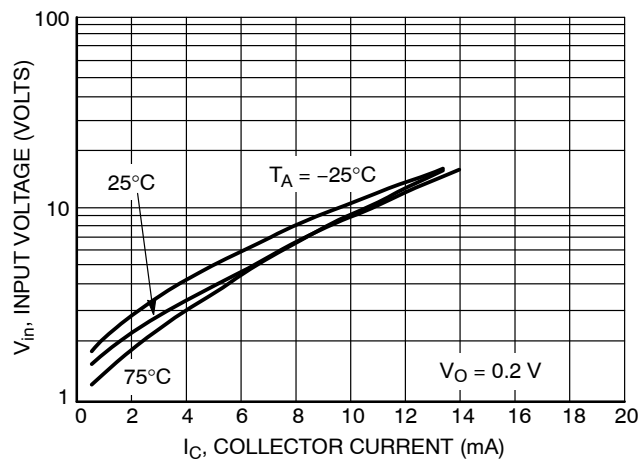


Figure 52. Input Voltage vs. Output Current

TYPICAL ELECTRICAL CHARACTERISTICS
LMUN2137LT1G

LMUN2110LT1G Series

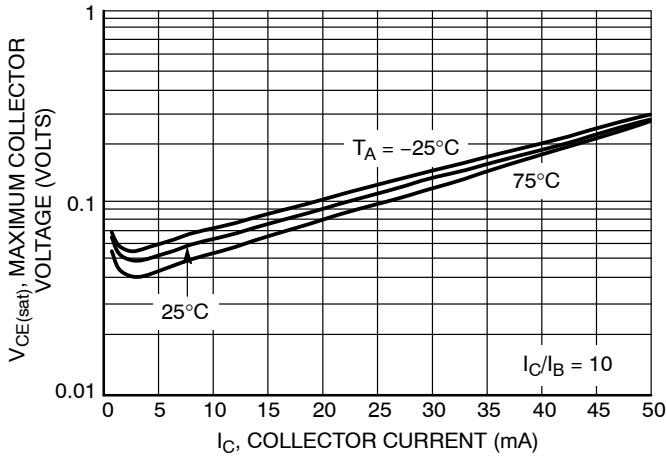


Figure 53. Maximum Collector Voltage vs. Collector Current

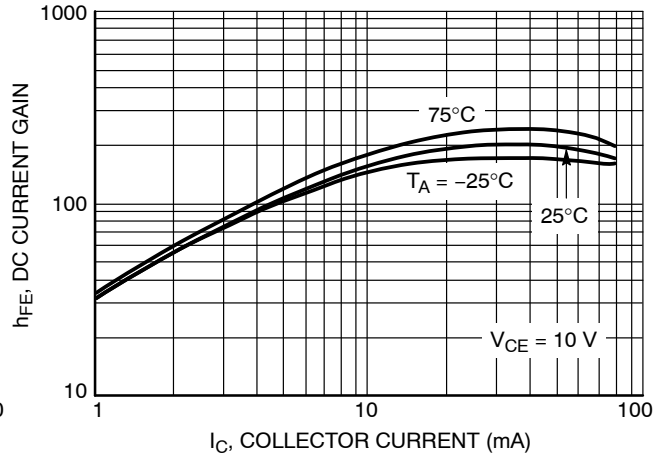


Figure 54. DC Current Gain

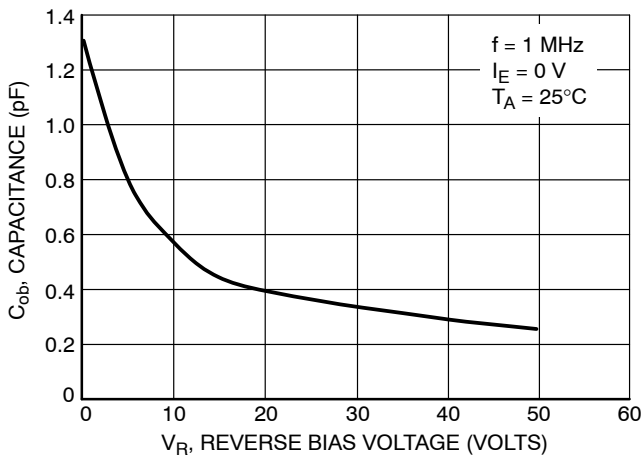


Figure 55. Output Capacitance

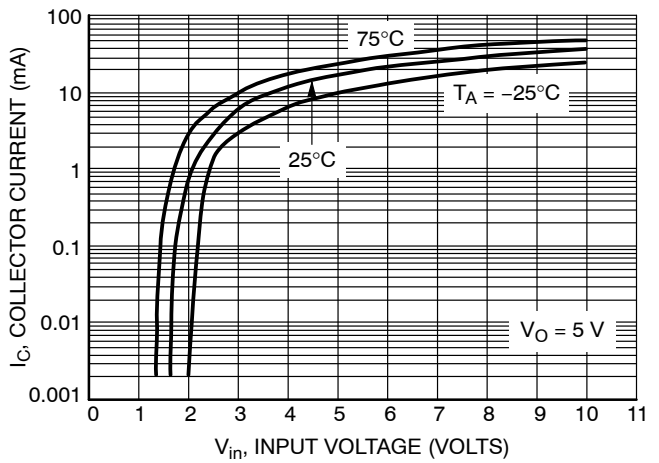


Figure 56. Output Current vs. Input Voltage

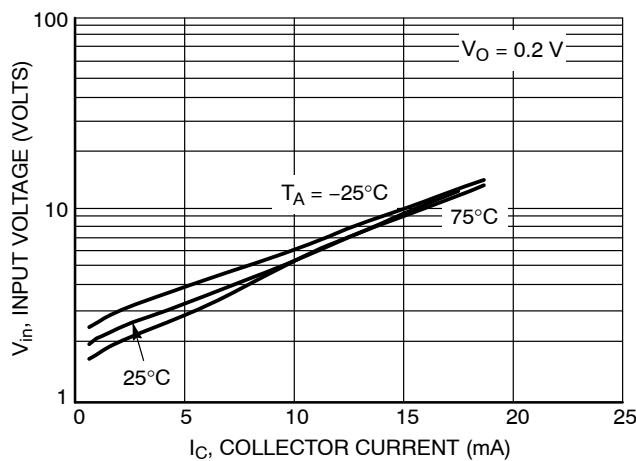
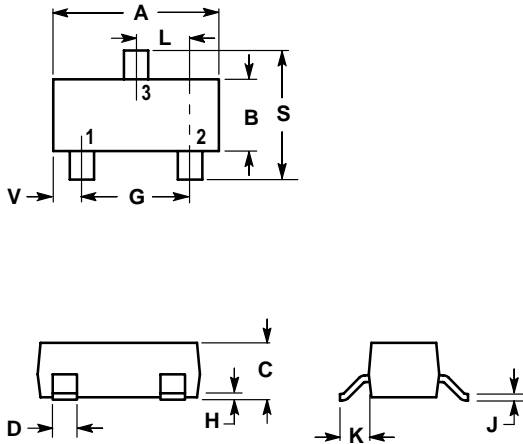


Figure 57. Input Voltage vs. Output Current

LMUN2110LT1G Series

SOT-23

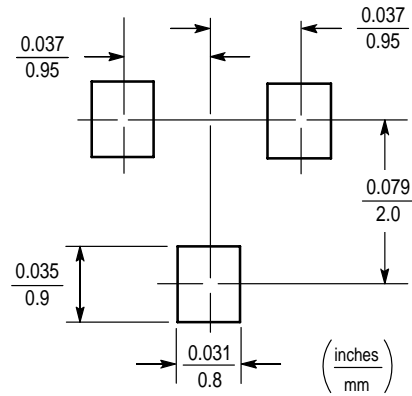


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. BASE
 2. EMITTER
 3. COLLECTOR



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Bipolar Transistors - Pre-Biased](#) category:

Click to view products by [Leshan](#) manufacturer:

Other Similar products are found below :

[RN1607\(TE85L,F\)](#) [DRC9A14E0L](#) [DTA124GKAT146](#) [DTA144WETL](#) [DTA144WKAT146](#) [DTC113EET1G](#) [DTC115TETL](#)
[DTC115TKAT146](#) [DTC124TETL](#) [DTC144VUAT106](#) [MUN5241T1G](#) [NSBA114TDP6T5G](#) [SMUN5330DW1T1G](#) [SSVMUN5312DW1T2G](#)
[RN1303\(TE85L,F\)](#) [RN1306\(TE85L,F\)](#) [RN4605\(TE85L,F\)](#) [TTEPROTOTYPE79](#) [EMH15T2R](#) [SMUN2214T3G](#) [SMUN5335DW1T1G](#)
[NSBC143ZPDP6T5G](#) [NSVMUN5113DW1T3G](#) [SMUN5230DW1T1G](#) [SMUN2214T1G](#) [FMA7AT148](#) [DTC114EUA-TP](#)
[NSVDTA114EET1G](#) [SMUN5237DW1T1G](#) [SMUN5213DW1T1G](#) [SMUN5114DW1T1G](#) [SMUN2111T1G](#) [DTC124ECA-TP](#)
[DTC123TM3T5G](#) [DTA114ECA-TP](#) [DTA113EM3T5G](#) [DTC113EM3T5G](#) [NSVMUN5135DW1T1G](#) [NSVMUN2237T1G](#)
[NSVDTC143ZM3T5G](#) [SMUN5335DW1T2G](#) [SMUN5216DW1T1G](#) [NSVMUN5316DW1T1G](#) [NSVMUN5215DW1T1G](#)
[NSVMUN5213DW1T3G](#) [NSVMUN2112T1G](#) [NSVIMD10AMT1G](#) [NSVEMC2DXV5T1G](#) [NSVDTC144WET1G](#) [NSVDTC123JET1G](#)